VS-6F(R) Series

Vishay Semiconductors



Standard Recovery Diodes, (Stud Version), 6 A



PRIMARY CHARACTERISTICS					
I _{F(AV)}	6 A				
Package	DO-4 (DO-203AA)				
Circuit configuration	Single				

FEATURES

- High surge current capability
- Stud cathode and stud anode version
- Wide current range
- Types up to 1200 V V_{RRM}
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- Battery charges

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		6	A		
I _{F(AV)}	T _C	160	°C		
I _{F(RMS)}		9.5	A		
IFSM	50 Hz	159	٨		
	60 Hz	167	- A		
l ² t	50 Hz	134	A ² s		
1-1	60 Hz	141	A-S		
V _{RRM}	Range	100 to 1200	V		
TJ		-65 to +175	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 175 °C mA			
	10	100	150				
	20	200	275				
	40	400	500				
VS-6F(R)	60	600	725	12			
	80	800	950				
	100	1000	1200				
	120	1200	1400				



Revision: 11-Jan-18

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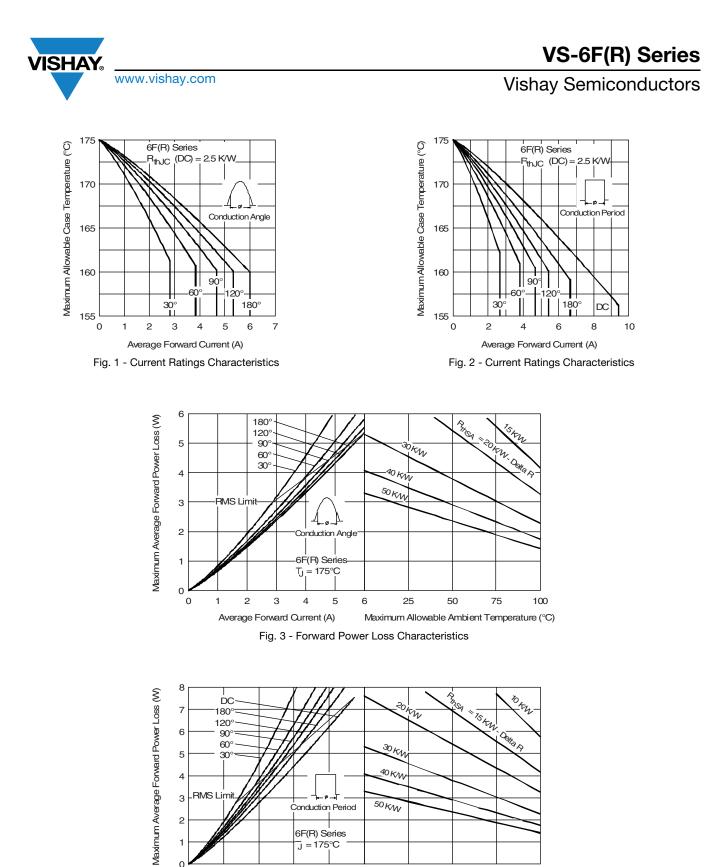
FORWARD CONDUCTION						
PARAMETER	SYMBOL		TEST CONDI	VALUES	UNITS	
Maximum average forward current	1	180° conduction, half sine wave			6	А
at case temperature	I _{F(AV)}		lion, nan sine wa	ve	160	°C
Maximum RMS forward current	I _{F(RMS)}				9.5	А
		t = 10 ms	No voltage		159	A
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied		167	
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM} reapplied		134	
		t = 8.3 ms		Sinusoidal half wave, initial T _J = T _J maximum	141	
Maximum I ² t for fusing		t = 10 ms	No voltage reapplied		127	A ² s
	l ² t	t = 8.3 ms			116	
		t = 10 ms	100 % V _{RRM}		90	
		t = 8.3 ms	reapplied		82	
Maximum I²√t for fusing	l²√t	t = 0.1 ms to	10 ms, no voltag	1270	A²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.63	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$			0.86	v
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), T _J = T _J maximum			15.7	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}),$	$T_J = T_J$ maximur	5.6	1112.2	
Maximum forward voltage drop	V _{FM}	I _{pk} = 19 A, T _J	= 25 °C, $t_p = 400$	1.10	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-65 to +175	0°	
Maximum storage temperature range	T _{Stg}		-65 to +200	C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	K/W	
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5	r./ vv	
Mounting torque, ± 10 %		Lubricated threads (Not lubricated threads)	1.2 (1.5)	N · m (lbf · in)	
Approximate weight			7	g	
Approximate weight			0.25	oz.	
Case style		See dimensions - link at the end of datasheet	DO-4 (DC)-203AA)	

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.34	0.29			
120°	0.44	0.48			
90°	0.57	0.63	$T_J = T_J maximum$	K/W	
60°	0.85	0.88			
30°	1.37	1.39			

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



10

Fig. 4 - Forward Power Loss Characteristics

25

50

Maximum Allowable Ambient Temperature (°C)

75

100

0

2

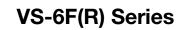
4

Average Forward Current (A)

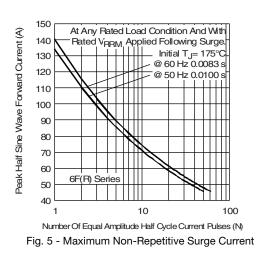
6

8





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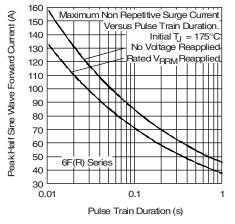
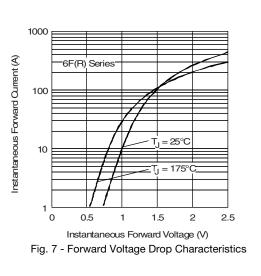


Fig. 6 - Maximum Non-Repetitive Surge Current





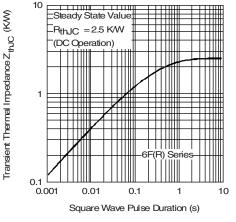


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

Device code	VS-	6	F	R	120	м
	1	2	3	4	5	6
	1 .	- Visł	nay Sem	niconduc	tors pro	duct
	2 -	- Cui	rrent rati	ing: cod	e = I _{F(AV}	/)
	3 -	- F=	standa	rd device	e	
	4			tud norn		
		• R	= stud	reverse	polarity	(anode
	5 -	Vol	tage coo	de x 10 :	= V _{RRM}	(see Vo
	6 -	• N	lone = s	tud base	e DO-4 (DO-20
		• N	1 = stud	base D0	D-4 (DO	-203AA

LINKS TO RELATED DOCUMENTS					
Dimensions	Dimensions www.vishay.com/doc?95311				
Revision: 11-Jan-18	4	Document Number: 93519			
For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com					
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R 0.40 R (0.02)

Ø 6.8 (0.27)

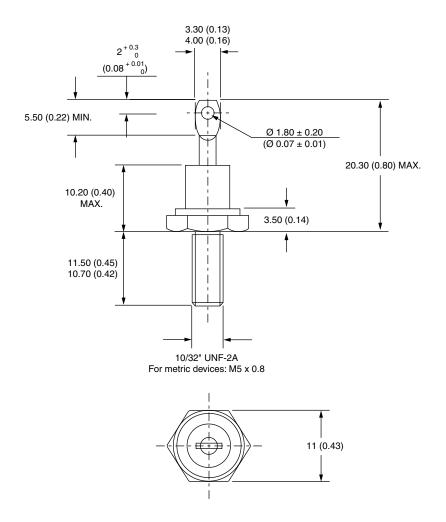
 0.8 ± 0.1

 (0.03 ± 0.004)



DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)







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